

PATENT ASSIGNMENT

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
Hongning Yang	04/03/2008
Jiang-Kai Zuo	04/03/2008
RECEIVING PARTY DATA	
Name:	FREESCALE SEMICONDUCTOR, INC.
Street Address:	6501 WILLIAM CANNON DRIVE WEST
City:	AUSTIN
State/Country:	TEXAS
Postal Code:	78735
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	12060105
CORRESPONDENCE DATA	
Fax Number:	(512)236-2173
<i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i>	
Phone:	512.236.2000
Email:	mmayer@jw.com
Correspondent Name:	Joseph P. Lally
Address Line 1:	100 Congress Avenue
Address Line 2:	Suite 1100
Address Line 4:	Austin, TEXAS 78701
ATTORNEY DOCKET NUMBER:	130704.00010
NAME OF SUBMITTER:	Mindy Mayer

CH \$40.00 12060105

Total Attachments: 3
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ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **Hongning Yang**, of 1834 E. Winchester Place, Chandler, Maricopa County, Arizona 85249, and **Jiang-Kai Zuo**, of 465 N. Laura Drive, Chandler, Maricopa County, Arizona 85225, have sold, assigned and transferred, and do hereby sell, assign and transfer, unto **FREESCALE SEMICONDUCTOR, INC.**, a corporation of the State of Delaware, having its principal office in Austin, State of Texas, United States of America, and its successors, assigns, and legal representatives, the entire right, title and interest for the United States of America in and to certain inventions relating to improvements in *Dual Gate Lateral Diffused MOS Transistor* (Docket No. MT10722ZP), described, illustrated and claimed in an application for Letters Patent of the United States of America executed by us on the dates indicated by our signatures below, filed on March 31, 2008 and assigned Application Serial No. 12/060105, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

We hereby also sell, assign and transfer unto **FREESCALE SEMICONDUCTOR, INC.**, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize **FREESCALE SEMICONDUCTOR, INC.** to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to **FREESCALE SEMICONDUCTOR, INC.**, for the sole use and benefit of **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign

